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TSSF4500

94 8688

Vishay Telefunken

# High Speed Infrared Emitting Diode in Side View Package

# Description

TSSF4500 is a high speed infrared emitting diode in GaAIAs on GaAIAs double hetero (DH) technology, molded in a clear, untinted plastic package with spherical side view lens.

The new technology combines the high speed of DH– GaAlAs with the efficiency of standard GaAlAs and the low forward voltage of the standard GaAs technology.

### **Features**

- High modulation bandwidth (10 MHz)
- Extra high radiant power and high radiant intensity
- Low forward voltage
- Suitable for high pulse current operation
- Angle of half intensity  $\varphi = \pm 22^{\circ}$
- Peak wavelength  $\lambda_p = 870$  nm
- High reliability
- Good spectral matching to Si photodetectors

## Applications

Infrared high speed remote control and free air data transmission systems with high modulation frequencies or high data transmission rate requirements.

TSSF4500 is ideal for the design of transmission systems according to IrDA requirements and for carrier frequency based systems (e.g. ASK / FSK – coded, 450 kHz or 1.3 MHz).

#### **Absolute Maximum Ratings**

T<sub>amb</sub> = 25°C

Parameter	Test Conditions	Symbol	Value	Unit
Reverse Voltage		VR	5	V
Forward Current	a sub-	IF	100	mA
Peak Forward Current	t <sub>p</sub> /T = 0.5, t <sub>p</sub> = 100 μs	I <sub>FM</sub>	200	mA
Surge Forward Current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1.5	Α
Power Dissipation		Pv	170	mW
Junction Temperature	COM	Т <sub>і</sub>	100	°C
Operating Temperature Range		T <sub>amb</sub>	-40+100	°C
Storage Temperature Range		T <sub>stg</sub>	-40+100	°C
Soldering Temperature	$t \leq 5sec, 2 mm from case$	T <sub>sd</sub> 260		°C
Thermal Resistance Junction/Ambient		R <sub>thJA</sub>	450	K/W



# **TSSF4500**

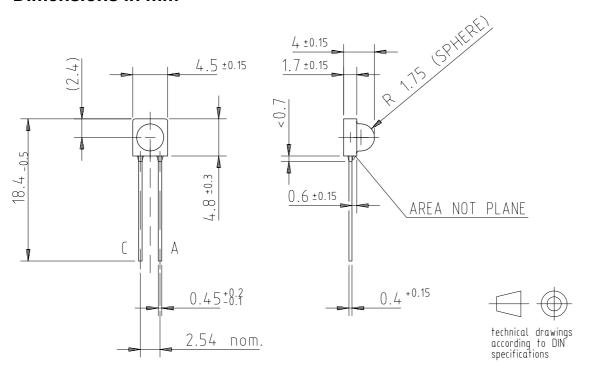
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## $T_{amb} = 25^{\circ}C$

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
Forward Voltage	I <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	VF		1.35	1.6	V
	I <sub>F</sub> = 1.5 A, t <sub>p</sub> = 100 μs	V <sub>F</sub>		2.4		V
Temp. Coefficient of V <sub>F</sub>	$I_F = 100 \text{mA}$	TK <sub>VF</sub>		-1.7		mV/K
Reverse Current	$V_R = 5 V$	I <sub>R</sub>			10	μΑ
Junction Capacitance	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0	Ci		160		pF
Radiant Intensity	I <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	l <sub>e</sub>	10	20		mW/sr
	$I_{\rm F} = 1 \text{ A}, t_{\rm p} = 100 \ \mu \text{s}$	Ι <sub>e</sub>		200		mW/sr
Radiant Power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	φ <sub>e</sub>		35		mW
Temp. Coefficient of $\phi_e$	I <sub>F</sub> = 100 mA	$TK_{\mathrm{\phi}e}$		-0.7		%/K
Angle of Half Intensity		φ		±22		deg
Peak Wavelength	I <sub>F</sub> = 100 mA	λρ		870		nm
Spectral Bandwidth	I <sub>F</sub> = 100 mA	Δλ		40		nm
Temp. Coefficient of $\lambda_p$	I <sub>F</sub> = 100 mA	TK <sub>λp</sub>		0.2		nm/K
Rise Time	I <sub>F</sub> = 100 mA	tr		30		ns
Fall Time	I <sub>F</sub> = 100 mA	t <sub>f</sub>		30		ns

# **Dimensions in mm**





9612206



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# **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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